







SN74AHC244-Q1

SCLS526B - JULY 2003 - REVISED AUGUST 2023

SN74AHC244-Q1 Automotive Octal Buffer/Driver with 3-State Outputs

1 Features

- Qualified for automotive applications
- EPIC™ (Enhanced-Performance Implanted CMOS) Process
- Operating range of 2-V to 5.5-V V_{CC}

2 Description

The SN74AHC244-Q1 contains one inverter gate. The device performs the Boolean function $Y = \overline{A}$.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾						
SN74AHC244-Q1	DBV (SOT-23, 5)	2.90 x 1.60 mm						
	DCK (SOT-SC70, 5)	2.00 x 1.25 mm						

- For all available packages, see the orderable addendum at the end of the data sheet.
- The package size (length x width) is a nominal value and includes pins, where applicable.

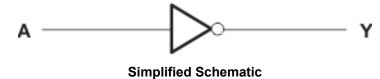




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3 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (April 2008) to Revision B (August 2023)

Page

Added Package Information table, Pin Functions table, ESD Ratings table, Thermal Information table, Device
Functional Modes, Device and Documentation Support section, and Mechanical, Packaging, and Orderable
Information section



4 Function Table

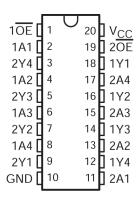


Figure 4-1. DW or PW Package (Top View)

Table 4-1. Pin Functions

	PIN		Table 4-1. Fill I diretions
NO.	NAME	I/O	DESCRIPTION
1	1 ŌE	I	Output Enable 1
2	1A1	I	1A1 Input
3	2Y4	0	2Y4 Output
4	1A2	I	1A2 Input
5	2Y3	0	2Y3 Output
6	1A3	I	1A3 Input
7	2Y2	0	2Y2 Output
8	1A4	I	1A4 Input
9	2Y1	0	2Y1 Output
10	GND	_	Ground pin
11	2A1	I	2A1 Input
12	1Y4	0	1Y4 Output
13	2A2	I	2A2 Input
14	1Y3	0	1Y3 Output
15	2A3	I	2A3 Input
16	1Y2	0	1Y2 Output
17	2A4	I	2A4 Input
18	1Y1	0	1Y1 Output
19	2 OE	I	Output Enable 2
20	VCC	_	Power Pin



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	7	V
V _I ²	Input voltage range		-0.5	7	V
V _O ²	Output voltage range		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	(V _I < 0)		-20	mA
I _{OK}	Output clamp current	$(V_O < 0 \text{ or } V_O > V_{CC})$		±20	mA
Io	Continuous output current	$(V_O = 0 \text{ to } V_{CC})$		±25	mA
	Continuous current through V _{CC} or GN	D		±50	mA
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5.2 ESD Ratings

				VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human body model (HBM), per AEC Q100-002 ¹	All pins	±1500	V

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage		2	5.5	V
		V _{CC} = 2 V	1.5		
V_{IH}	High-level input voltage	V _{CC} = 3 V	2.1		V
		V _{CC} = 5.5 V	3.85		
		V _{CC} = 2 V		0.5	
V _{IL}	Low-level input voltage	V _{CC} = 3 V		0.9	V
		V _{CC} = 5.5 V		1.65	
VI	Input voltage	·	0	5.5	V
Vo	Output voltage		0	V _{CC}	V
		V _{CC} = 2 V		-50	μA
I _{OH}	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		-4	Л
		V _{CC} = 5 V ± 0.5 V		-8	mA
		V _{CC} = 2 V		50	mA
I_{OL}	Low-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4	m Λ
		V _{CC} = 5 V ± 0.5 V		8	mA
A 4 / A > .	Innut transition via ar fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		100	no/\/
Δt/Δv	Input transition rise or fall rate	$V_{CC} = 5 V \pm 0.5 V$		20	ns/V
T _A	Operating free-air temperature		-40	125	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND for proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

⁽²⁾ The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

5.4 Thermal Information

		SN74AHC		
	THERMAL METRIC(1)	DW PW		UNIT
		20 PINS	20 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	58	83	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

5.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V	T _A = 2	5°C	MIN MAX	UNIT
PANAMETER		V _{cc}	MIN 7	TYP MAX	IVIIIN IVIAA	ONIT
		2 V	1.9	2	1.9	
	I _{OH} = -50 μA	3 V	2.9	3	2.9	
V _{OH}		4.5 V	4.4	4.5	4.4	V
	I _{OH} = -4 mA	3 V	2.58		2.48	
	I _{OH} = −8 mA	4.5 V	3.94		3.8	
	I _{OL} = 50 μA	2 V		0.1	0.1	
		3 V		0.1	0.1	
V _{OL}		4.5 V		0.1	0.1	V
	I _{OL} = 4 mA	3 V		0.36	0.5	
	I _{OL} = 8 mA	4.5 V		0.36	0.5	
I _I	V _I = 5.5 V or GND	0 V to 5.5 V		±0.1	±1	μA
I _{OZ}	$V_O = V_{CC}$ or GND, $V_I (\overline{OE}) = V_{IL}$ or V_{IH}	5.5 V		±0.25	±2.5	μA
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V		4	40	μA
C _i	V _I = V _{CC} or GND	5 V		2 10		pF
C _o	V _O = V _{CC} or GND	5 V		3.5		pF

5.6 Switching Characteristics

over recommended operating free-air temperature range, V_{CC} = 3.3 V ± 0.3 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD	T _A = 25°C		MIN	MAX	UNIT
PARAMETER	PROW (INPUT)	10 (001701)	CAPACITANCE	MIN TYP	MAX	IVIIIV	IVIAA	UNIT
t _{PLH}	А	Y	C _L = 15 pF	5.8	8.4	1	10	ns
t _{PHL}	^	I I	C _L = 13 μr	5.8	8.4	1	10	115
t _{PZH}	ŌĒ	Y	C _L = 15 pF	6.6	10.6	1	12.5	ns
t _{PZL}	OL	I I	C _L = 13 μr	6.6	10.6	1	12.5	115
t _{PHZ}	- OE	Y	C ₁ = 15 pF	5	9.7	1	11	ns
t _{PLZ}	OL	I I	C _L = 13 μr	5	9.7	1	11	115
t _{PLH}	А	Y	C _L = 50 pF	8.3	11.9	1	13.5	ns
t _{PHL}	A	ľ	C _L = 50 pr	8.3	11.9	1	13.5	115
t _{PZH}	ŌĒ	Y	C _L = 50 pF	9.1	14.1	1	16	ns
t _{PZL}	OE .	.	OL = 50 pr	9.1	14.1	1	16	115
t _{PHZ}	ŌĒ	Υ	C _L = 50 pF	10.3	14	1	16	ne
t _{PLZ}	OE	.	O _L = 50 pr	10.3	14	1	16	ns



5.7 Switching Characteristics

over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	EDOM (INDUT)	TO (OUTPUT)	LOAD	T _A = 25°C			MIN	MAX	UNIT	
PARAWEIER	FROM (INPUT)	TO (OUTPUT)	CAPACITANCE	MIN	TYP	MAX	WIN WAZ	WAX	UNII	
t _{PLH}	A	Υ	C _L = 15 pF		3.9	5.5	1	6.5	ns	
t _{PHL}		ı	CL = 13 pr		3.9	5.5	1	6.5	115	
t _{PZH}	ŌĒ	Υ	C _L = 15 pF		4.7	7.3	1	8.5	ns	
t _{PZL}	- OE	I	C _L = 13 pr		4.7	7.3	1	8.5	115	
t _{PHZ}	- OE	Υ	C _L = 15 pF		5	7.2	1	8.5	ns	
t _{PLZ}	OL	ı	CL = 13 pr		5	7.2	1	8.5	115	
t _{PLH}	A	Υ	C _L = 50 pF		5.4	7.5	1	8.5	ns	
t _{PHL}		ı	CL = 30 pr		5.4	7.5	1	8.5	115	
t _{PZH}	ŌĒ	Υ	C = 50 pE		6.2	9.3	1	10.5	no	
t _{PZL}) OE	Y C _L = 50 pF			6.2	9.3	1	10.5	ns	
t _{PHZ}	ŌĒ	Υ	C _L = 50 pF		6.7	9.2	1	10.5	nc	
t _{PLZ}) OE	T	GL = 50 pr		6.7	9.2	1	10.5	ns	

5.8 Noise Characteristics

 $V_{CC} = 5 \text{ V}, C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C}^{(1)}$

	PARAMETER	MIN	TYP	MAX	UNIT
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.5		V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		-0.2		V
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}		4.8		V
V _{IH(D)}	High-level dynamic input voltage	3.5			V
$V_{IL(D)}$	Low-level dynamic input voltage			1.5	V

⁽¹⁾ Characteristics are for surface-mount packages only.

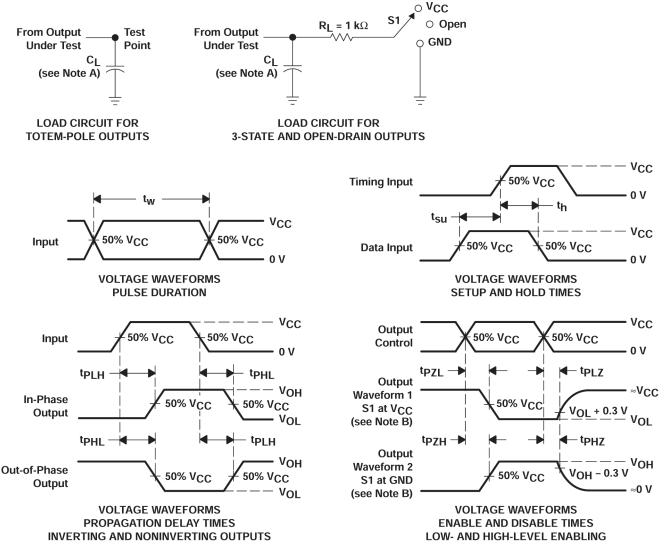
5.9 Operating Characteristics

 $V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C}$

PARAMETER		TEST CONDITIONS		TYP	UNIT
C_{pd}	Power dissipation capacitance	No load,	f = 1 MHz	8.6	pF



6 Parameter Measurement Information



- A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_r \leq$ 3 ns, $t_f \leq$ 3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 6-1. Load Circuit and Voltage Waveforms

TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V _{CC}
t _{PHZ} /t _{PZH}	GND
Open Drain	V _{CC}



7 Detailed Description

7.1 Overview

This octal buffer/driver is designed specifically to improve the performance and density of 3-state memory-address drivers, clock drivers, and bus-oriented receivers and transmitters.

The SN74AHC244 is organized as two 4-bit buffers/line drivers with separate output-enable (\overline{OE}) inputs. When \overline{OE} is low, the device passes data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state.

For the specified high-impedance state during power up or power down, \overline{OE} must be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

7.2 Functional Block Diagram

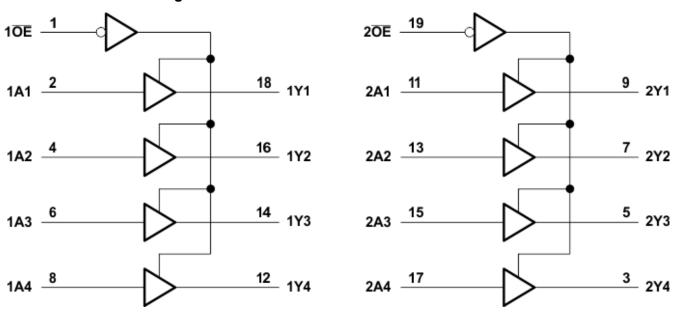
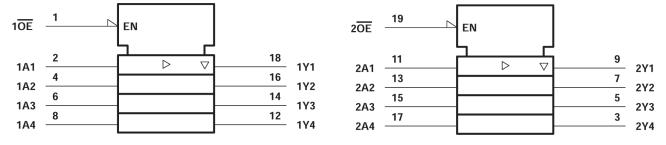


Figure 7-1. Logic Diagram (Positive Logic)



This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Figure 7-2. Logic Symbol



7.3 Device Functional Modes

Table 7-1. (Each 4-Bit Buffer/Driver)

INPU	TS	OUTPUT Y
ŌĒ	Α	COIPOIT
L	Н	Н
L	L	L
Н	Х	Z

8 Device and Documentation Support

8.1 Documentation Support

8.1.1 Related Documentation

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 8-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN74AHC244-Q1	Click here	Click here	Click here	Click here	Click here

8.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

8.4 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

8.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.6 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

9 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
017441100440014004	A OTIV / E	0010	DW	-00	0000	D-110 0 0	(6)	1 1 4 0000 LINU IM	40.1- 405	111004404	
SN74AHC244QDWRQ1	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC244Q1	Samples
SN74AHC244QPWRG4Q1	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC244Q1	Samples
SN74AHC244QPWRQ1	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC244Q1	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN74AHC244-Q1:

Catalog : SN74AHC244

● Enhanced Product : SN74AHC244-EP

Military: SN54AHC244

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

• Military - QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHC244QDWRQ1	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74AHC244QPWRG4Q1	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74AHC244QPWRQ1	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1



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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHC244QDWRQ1	SOIC	DW	20	2000	367.0	367.0	45.0
SN74AHC244QPWRG4Q1	TSSOP	PW	20	2000	356.0	356.0	35.0
SN74AHC244QPWRQ1	TSSOP	PW	20	2000	356.0	356.0	35.0



SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES:

- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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